





ZMJ SEMICONDUCTOR CO., LTD

**ZM040N06D**  
**60V N-Channel Power MOSFET**

**Thermal resistance**

Parameter	Symbol	Min.	Typ.	Max.	Unit
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Fig.1 Gate-Charge Characteristics

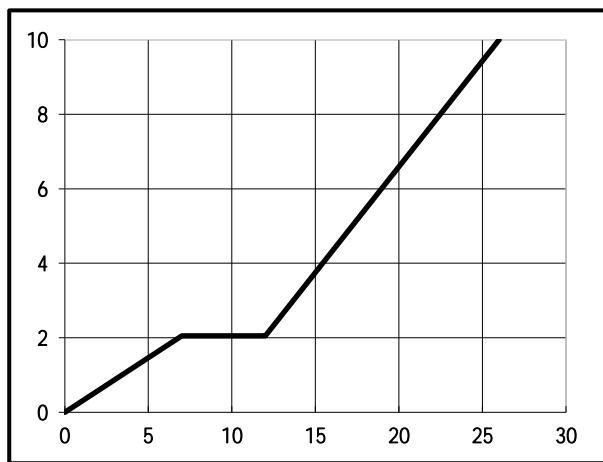


Fig.2 Capacitance Characteristics

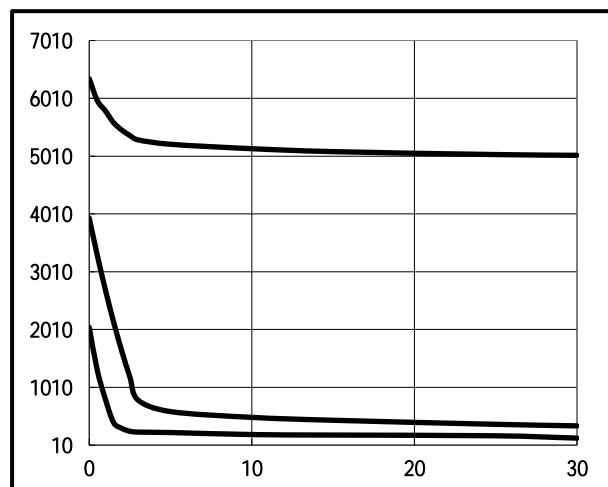


Fig.3 Power Dissipation

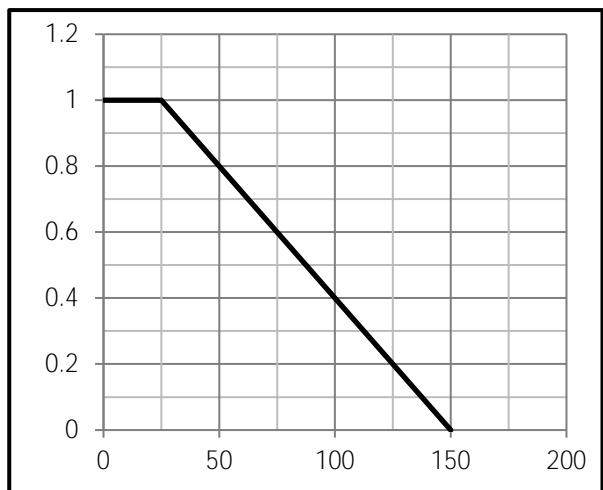


Fig.4 Typical output Characteristics

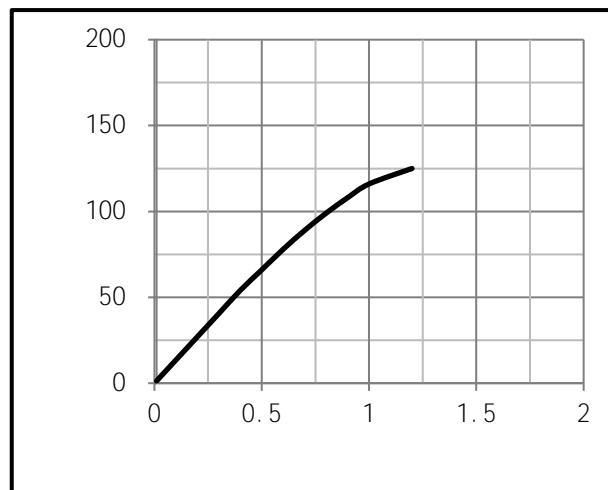


Fig.5 Threshold Voltage V.S Junction Temperature

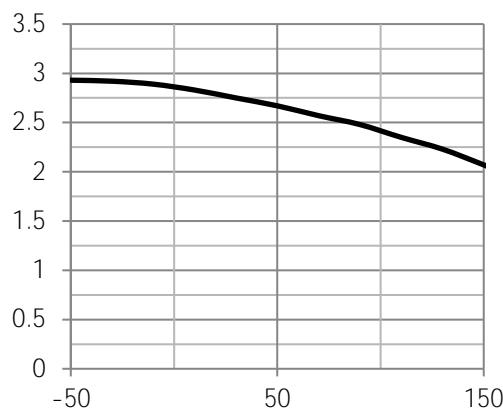


Fig.6 Resistance V.S Drain Current





Fig.13 Switching Time Measurement Circuit

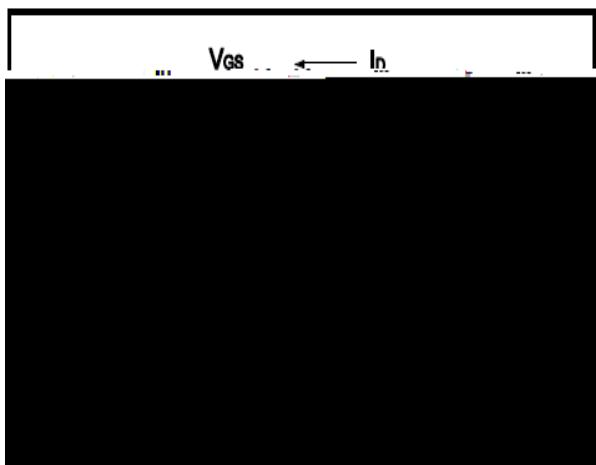
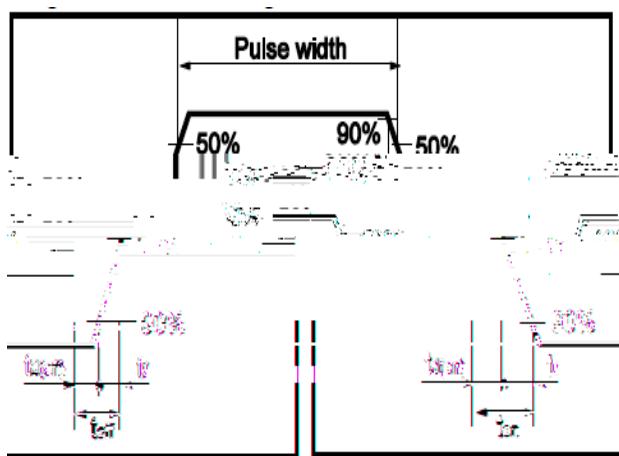


Fig.14 Gate Charge Waveform





## Dimensions (TO-252)

Unit mm

SYMBOL	min	max	SYMBOL	min	max
A	2.10	2.50	B	0.85	1.25
b	0.50	0.80	b1	0.50	0.90
b2	0.45	0.70	C	0.45	0.70
D	6.30	6.75	D1	5.10	5.50
E	5.30	6.30	e1	2.25	2.35
L1	9.20	10.60	e2	4.45	4.75
L2	0.90	1.75	L3	0.60	1.10
K	0.00	0.23			

